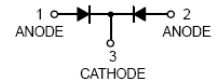


Features

- Fast switching speed
- High conductance

HF



Mechanical Data

- Case: SOT-523
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208



Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
BAV70T	SOT-523	3000 pcs / Tape & Reel	JJ

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Repetitive Peak Reverse Voltage	V _{RRM}	85	V
DC Blocking Voltage	V _R	75	V
Forward Continuous Current	I _F	150	mA
Repetitive Peak Forward Current	I _{FRM}	500	mA
Peak Forward Surge Current, 1μs Single Half-sine-wave	I _{FSM}	4	A
Peak Forward Surge Current, 1ms Single Half-sine-wave	I _{FSM}	1	A
Peak Forward Surge Current, 1s Single Half-sine-wave	I _{FSM}	0.5	A

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation (T _S = 90°C, one diode loaded)	P _D	170	mW
Operating Junction Temperature Range	T _J	-65 ~ +150	°C
Storage Temperature Range	T _{STG}	-65 ~ +150	°C

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage	$V_{(BR)R}$	$I_R = 2.5\mu\text{A}$	75	-	-	V
Forward Voltage	V_F	$I_F = 1\text{mA}$	-	-	0.715	V
		$I_F = 10\text{mA}$	-	-	0.855	V
		$I_F = 50\text{mA}$	-	-	1.000	V
		$I_F = 150\text{mA}$	-	-	1.250	V
Maximum Peak Reverse Current	I_R	$V_R = 25\text{V}$	-	-	30	nA
		$V_R = 75\text{V}$	-	-	2	μA
		$V_R = 25\text{V}, T_J = 150^\circ\text{C}$	-	-	60	μA
		$V_R = 75\text{V}, T_J = 150^\circ\text{C}$	-	-	100	μA
Total Capacitance	C_J	$V_R = 0\text{V}, f = 1.0\text{MHz}$	-	-	1.5	pF
Reverse Recovery Time	t_{rr}	$I_F = I_R = 10\text{mA}$ $I_{rr} = 0.1 \times I_R, R_L = 100\Omega$	-	-	4	ns

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

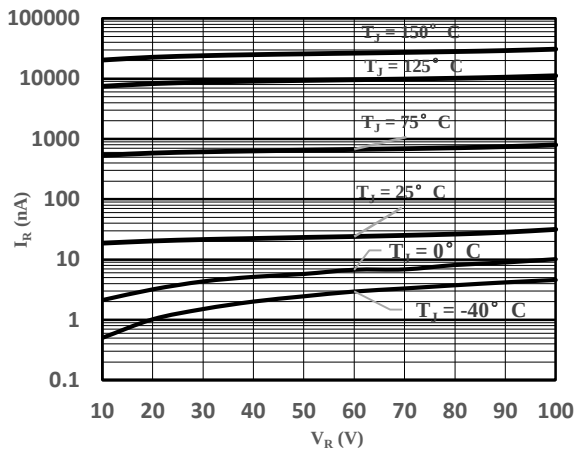


Fig 1 Typical Reverse Characteristic

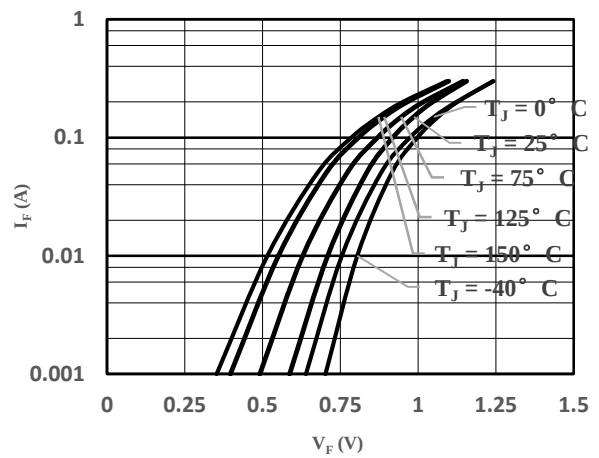


Fig 2 Typical Forward Characteristics

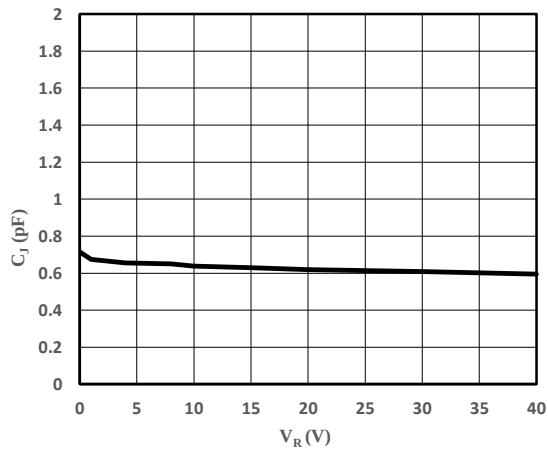
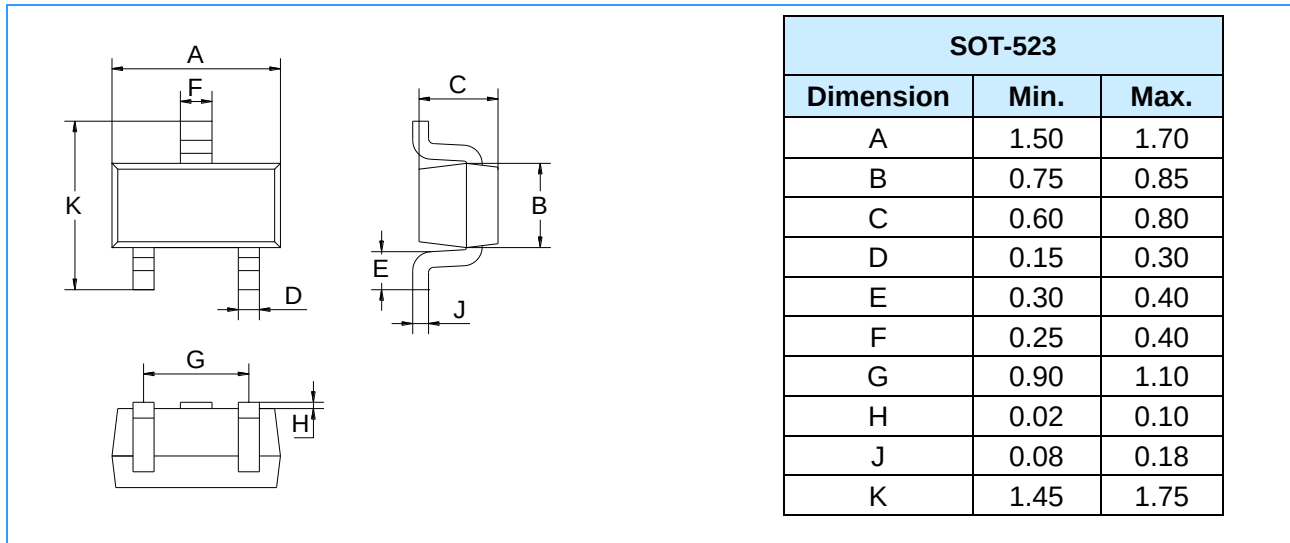
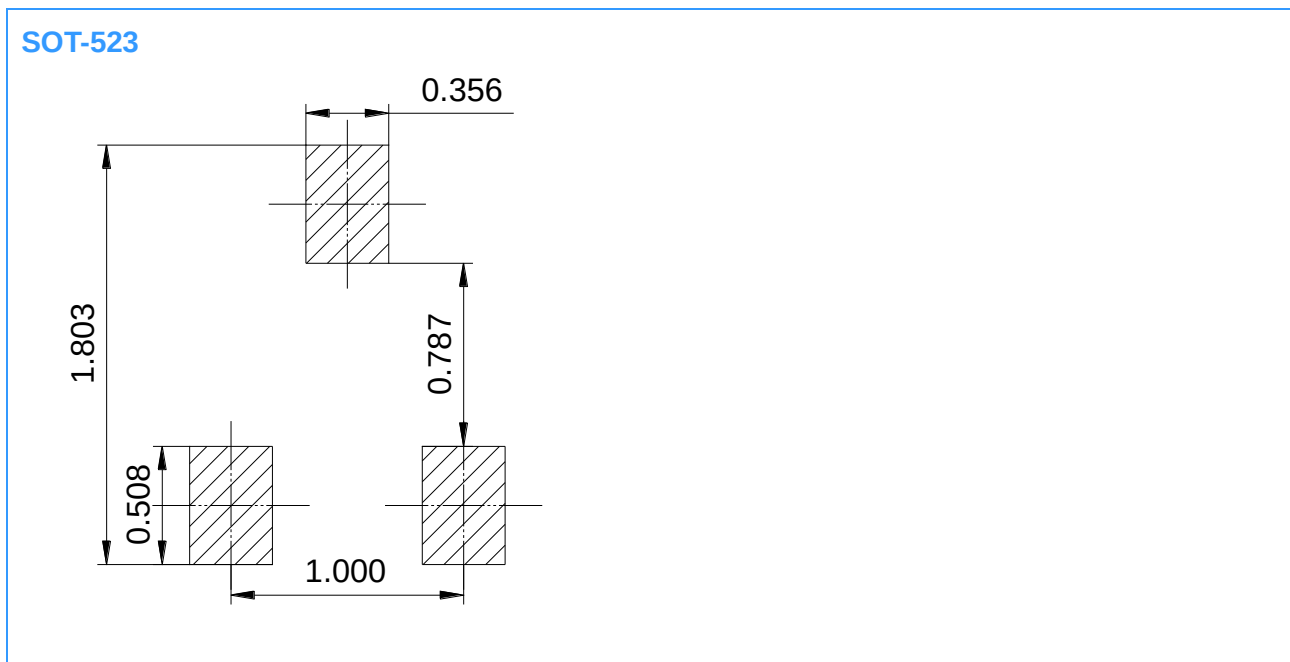


Fig 3 Capacitance vs. Reverse Voltage

Package Outline Dimensions (Unit: mm)



Mounting Pad Layout (Unit: mm)



Important Notice

Changzhou Galaxy Century Microelectronics (GME) reserves the right to make changes without further notice to any product information (copyrighted) herein to make corrections, modifications, improvements, or other changes. GME does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others.